



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Attorney Docket N. 040373/0300

Applicant: Toshiyuki HIROTA et al.

Title: SEMICONDUCTOR DEVICE WITH HIGH- AND LOW-DENSITY REGIONS OF TRANSISTOR ELEMENTS ON SINGLE SEMICONDUCTOR SUBSTRATE, AND METHOD OF MANUFACTURING SUCH SEMICONDUCTOR DEVICE

Serial No.: 09/741,195

Filed: December 21, 2000

Examiner: Vu, Quang D.

Art Unit: 2811

AMENDMENT AND REPLY TO 37 C.F.R. § 1.111

Commissioner for Patents
Washington, D.C. 20231

Sir:

In reply to the Office Action dated January 30, 2003, please amend the application as follows:

IN THE CLAIMS:

In accordance with 37 C.F.R. § 1.121, please substitute for presently pending claims 1, 6, 11, 18 and 29-32, the following rewritten versions of the same claims, as amended. The changes are shown explicitly in the attached "Marked Up Version Showing Changes Made."

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